

# **BDS-MM Family Picosecond Diode Lasers**

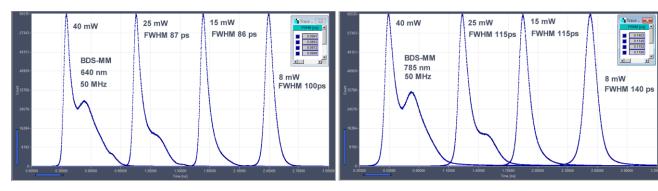
# Optical power up to 60 mW @ 50 MHz

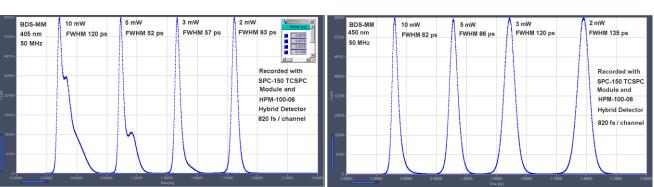
Small-size module, 40 x 40 x 120 mm³ or 40 x 70 x 120 mm³ Wavelengths 405, 445, 525, 640, 685, 785, 915 nm Power up to 60 mW, multi-mode @ 50 MHz Free-beam or multi-mode fibre output Pulse repetition rate 20 MHz and 50 MHz, others on request Ext. trigger via sync. input: 20 to 50 MHz, others on request Fast ON/OFF and multiplexing capability High power stability

All electronics integrated, no external driver unit required Simple +12 V power supply

Compatible with all bh TCSPC devices







Pulse shapes may change due to development in laser diode performance. Power measured in free beam. Coupling efficiency into optical fibres is 60 to 90%, depending on fibre diameter

# Designed and manufactured by



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# DS-MM

Trigger Output for TCSPC Synchronisation

H 4.00ns A Ch1 J -560m

#### Optical

Repetition Rate, switchabel by TTL signal Wavelengths

Max. optical power

Coupling efficiency into fibres (multi-mode, typical values)
Pulse width (FWHM, at medium power)

Pulse width (FWHM, at maximum power)

Warm-up time for power and pulse shape stabilisation after power on

## **Trigger Output, to TCSPC Modules**

Pulse Amplitude Pulse Width Output Impedance Connector

Jitter between Trigger and Optical Pulse

#### **Synchronisation Input**

Input amplitude

Duty cycle

Input frequency

Connector Switch between internal clock and sync input

#### **Control Inputs**

Laser ON/OFF

Response of optical output to ON/OFF signal

External Power Control

Response time of optical output to power control

F1: 50 MHz

F2: 20 MHz

#### **Power Supply**

Power Supply Voltage Power Supply Current at 12V

#### **Mechanical Data**

Dimensions (OEM) Dimensions (w/ cooling) Mounting holes

Heat sink requirements

### **Connector Pin Assignment**

Connector version Power supply +12V

**GND** 

Power control voltage

Laser ON/OFF (active H) F1: 50 MHz (active H, internal pull-up resistor)

F2: 20 MHz (active H, internal pull-down resistor)

Do not connect:

### **Maximum Values**

Power Supply Voltage

Voltage at 'Laser ON/OFF' and 'Frequency' inputs

Voltage at 'Laser Power' input

Ambient Temperature

- 1) Operation below 15 °C ambient temperature may result in extended warm-up time.
- 2) Depends on case temperature due to laser diode cooling. Cooling current changes with case temperature.
- 3) OEM version without active cooling must be mounted on heat sink. Case temperature must remain below 40 °C.

## Related Products

BDS-SM picosecond diode lasers, BDS-SMN picosecond and CW diode lasers, 375, 405, 445, 473, 488, 515, 640, 685, 785, 1064 nm





Caution: Class 3B laser product. Avoid direct eye exposure. Light emitted by the device may be harmful to the human eye. Please obey laser safety rules when operating the devices. Complies with US federal laser product performance standards.

# International Sales Representatives



US: **Boston Electronics Corp** tcspc@boselec.com www.boselec.com



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20 MHz and 50 MHz, other combinations on request 405, 450, 525, 640, 685, 785, 915 nm, others on request 10 to 60 mW at 50 MHz, depends on wavelength version  $100~\mu m$ :  $60\% - 200~\mu m$ :  $80~\% - 500~\mu m$ : 90~%65 to 120 ps 120 to 300 ps 1 min 1)

> -1 V (peak) into 50 Ω 1 ns, see figure right 50 Ω SMA < 10 ps

+3.3 to +5 V into 50 Ω 10 to 30 %. DC equivalent must be < 2.5V 20 to 50 MHz, others on request SMA automatic, by average voltage at trigger connector

TTL / CMOS, 'low' means 'OFF', internal pull-up < 4 us for power 10 to 100 %, see figures right analog input, 0 to + 10 V < 4 us for power 10 to 100 %, see figure right active H, internal pull-up resistor active H, internal pull-down resistor

Laser runs at 50 MHz with Frequency inputs unconnected + 9 V to +15 V200 mA to 500 mA  $^{2)}$ 

> 40 mm x 40 mm x 120 mm 40 mm x 70 mm x 120 mm four holes for M3 screws  $< 2^{\circ}C / W^{3)}$

> > 1, 2

8

6

7

9 to 15

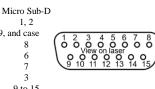
0 V to +15 V

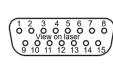
-12 V to + 12 V

15 °C to +35 °C 3)

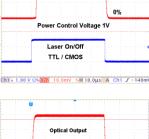
-2 V to +7 V

4, 5, 9, and case









er Control Voltage 10V

GNI + 1.00 V Ω%Ch2 100mV %H 10.0µs A Ch1 J-140m

Optical Output

10 us/div

Laser On/Off

TTL / CMOS